

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

CPH3360 — General-Purpose Switching Device Applications

Features

- ON-resistance RDS(on)1=233m Ω (typ.)
- · 4V drive
- · Halogen free compliance

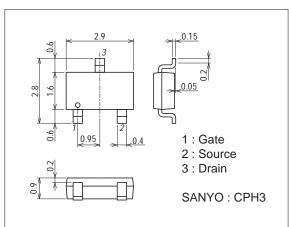
Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		-1.6	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-6.4	А
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm ² x0.8mm)	0.9	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

unit : mm (typ) 7015A-004



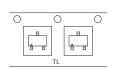
Product & Package Information

• Package : CPH3

• JEITA, JEDEC : SC-59, TO-236, SOT-23

• Minimum Packing Quantity : 3,000 pcs./reel

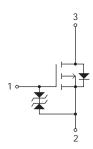
Packing Type: TL



Marking



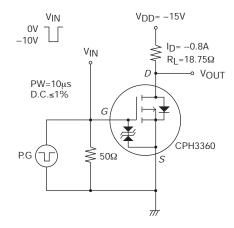
Electrical Connection

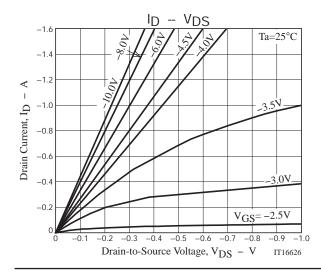


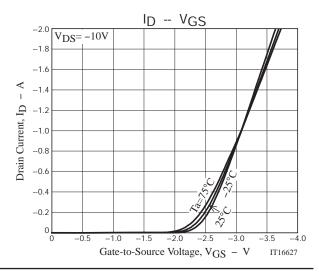
Electrical Characteristics at Ta=25°C

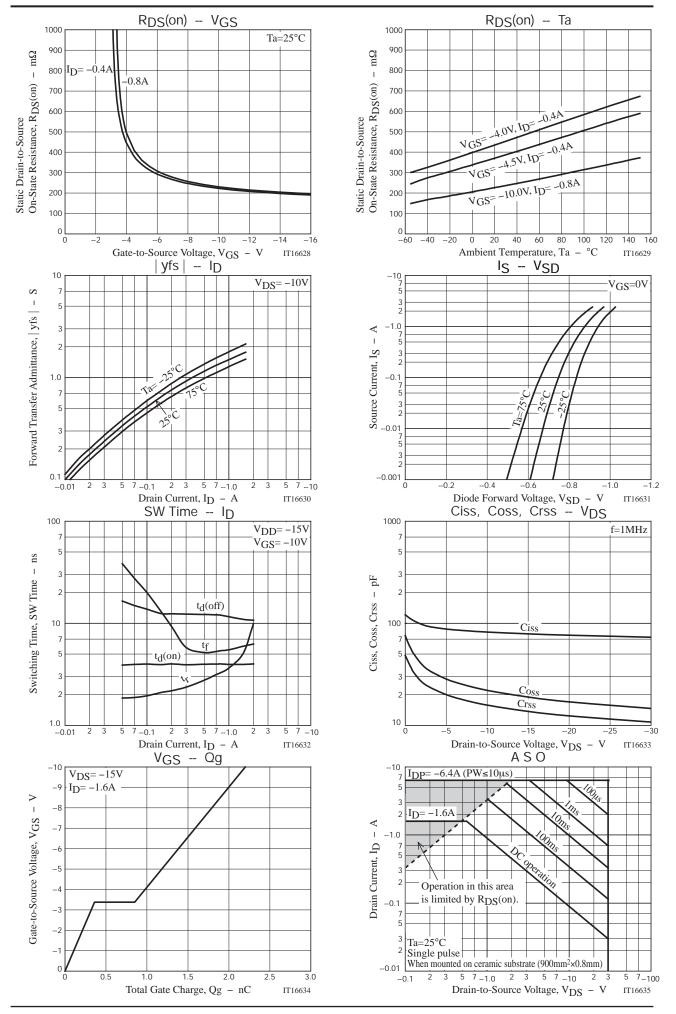
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-30V, V _{GS} =0V			-1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	yfs	VDS=-10V, ID=-0.8A		1.3		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =-0.8A, V _G S=-10V		233	303	mΩ
	R _{DS} (on)2	I _D =-0.4A, V _G S=-4.5V		380	532	mΩ
	R _{DS} (on)3	I _D =-0.4A, V _G S=-4V		441	617	mΩ
Input Capacitance	Ciss	V _{DS} =-10V, f=1MHz		82		pF
Output Capacitance	Coss			22		pF
Reverse Transfer Capacitance	Crss			16		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		4.0		ns
Rise Time	tr			3.3		ns
Turn-OFF Delay Time	t _d (off)			12		ns
Fall Time	tf			5.4		ns
Total Gate Charge	Qg	V _{DS} =-15V, V _{GS} =-10V, I _D =-1.6A		2.2		nC
Gate-to-Source Charge	Qgs			0.36		nC
Gate-to-Drain "Miller" Charge	Qgd			0.49		nC
Diode Forward Voltage	V _{SD}	IS=-1.6A, VGS=0V		-0.9	-1.5	V

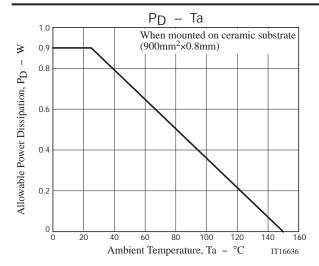
Switching Time Test Circuit











Note on usage: Since the CPH3360 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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